VHF 36

## Half Controlled <br> Single Phase Rectifier Bridge

with Freewheeling Diode

| $\mathbf{V}_{\text {RSM }}$ | $\mathbf{V}_{\text {RRM }}$ | Type |
| :---: | :---: | :--- |
| $V_{\text {DSM }}$ | $V_{\text {DRM }}$ |  |
| $V$ | V |  |
| 900 | 800 | VHF 36-08io5 |
| 1300 | 1200 | VHF 36-12io5 |
| 1500 | 1400 | VHF 36-14io5 |
| 1700 | 1600 | VHF 36-16io5 |



$\mathrm{I}_{\mathrm{dAVM}}=40 \mathrm{~A}$<br>$\mathrm{V}_{\text {RRM }}=800-1600 \mathrm{~V}$



| Symbol | Test Conditions |  | Maximum Ratings |  |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{dAV}}$ | $\mathrm{T}_{\mathrm{K}}=85^{\circ} \mathrm{C}$, module |  | 36 | A |
| $\mathrm{I}_{\mathrm{dAVm}}{ }^{(1)}$ | module |  | 40 | A |
| $\mathrm{I}_{\text {fRMS }}, \mathrm{I}_{\text {TRMS }}$ | per leg |  | 28 | A |
| $\mathrm{I}_{\text {FSM }}, \mathrm{I}_{\text {TSM }}$ | $\mathrm{T}_{\mathrm{VJ}}=45^{\circ} \mathrm{C}$; | $\mathrm{t}=10 \mathrm{~ms}(50 \mathrm{~Hz})$, sine | 320 | A |
|  | $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}$ | $\mathrm{t}=8.3 \mathrm{~ms}(60 \mathrm{~Hz})$, sine | 350 | A |
|  | $\mathrm{T}_{\mathrm{VJ}}=\mathrm{T}_{\text {VJM }}$ | $\mathrm{t}=10 \mathrm{~ms}(50 \mathrm{~Hz})$, sine | 280 | A |
|  | $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}$ | $\mathrm{t}=8.3 \mathrm{~ms}(60 \mathrm{~Hz})$, sine | 310 | A |
| $\mathrm{I}^{2} \mathrm{t}$ | $\mathrm{T}_{\mathrm{VJ}}=45^{\circ} \mathrm{C}$ | $\mathrm{t}=10 \mathrm{~ms}(50 \mathrm{~Hz})$, sine | 500 | $\mathrm{A}^{2} \mathrm{~S}$ |
|  | $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}$ | $\mathrm{t}=8.3 \mathrm{~ms}(60 \mathrm{~Hz})$, sine | 520 | $A^{2} \mathrm{~S}$ |
|  | $\mathrm{T}_{\mathrm{VJ}}=\mathrm{T}_{\text {VJM }}$ | $\mathrm{t}=10 \mathrm{~ms} \mathrm{(50} \mathrm{Hz)}$, | 390 | $\mathrm{A}^{2} \mathrm{~S}$ |
|  | $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}$ | $\mathrm{t}=8.3 \mathrm{~ms}(60 \mathrm{~Hz})$, sine | 400 | $A^{2} \mathrm{~s}$ |
| (di/dt) ${ }_{\text {cr }}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{Vv}}=125^{\circ} \mathrm{C} \\ & \mathrm{f}=50 \mathrm{~Hz}, \mathrm{t}_{\mathrm{P}}=200 \mu \mathrm{~s} \\ & \mathrm{~V}_{\mathrm{D}}=2 / 3 \mathrm{~V} \mathrm{~V}_{\mathrm{DRM}} \\ & \mathrm{I}_{\mathrm{G}}=0.3 \mathrm{~A}, \\ & \mathrm{di}_{\mathrm{G}} / \mathrm{dt}=0.3 \mathrm{~A} / \mu \mathrm{s} \\ & \hline \end{aligned}$ | repetitive, $\mathrm{I}_{T}=50 \mathrm{~A}$ | 150 | A/ $/ \mathrm{S}$ |
|  |  |  |  |  |
|  |  | non repetitive, $I_{T}=1 / 2 \cdot I_{\text {dAV }}$ | 500 | A/ $/ \mathrm{S}$ |
| (dv/dt) ${ }_{\text {cr }}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{VJ}}=\mathrm{T}_{\mathrm{VMM}} ; \mathrm{V}_{\mathrm{DR}}=2 / 3 \mathrm{~V}_{\mathrm{DRM}} \\ & \mathrm{R}_{\mathrm{GK}}=\infty ; \text { method } 1 \text { (linear voltage rise) } \end{aligned}$ |  | 1000 | V/ $/ \mathrm{S}$ |
| $\mathrm{V}_{\text {RGM }}$ |  |  | 10 | V |
| $\mathrm{P}_{\mathrm{Gm}}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{VJ}}=\mathrm{T}_{\mathrm{VJM}} \\ & \mathrm{I}_{\mathrm{T}}=\mathrm{I}_{\mathrm{TAVM}} \end{aligned}$ | $\mathrm{t}_{\mathrm{p}}=30 \mu \mathrm{~s}$ | $\leq 10$ | W |
|  |  | $t_{p}=500 \mu s$ | $\leq 5$ | W |
|  |  | $\mathrm{t}_{\mathrm{p}}=10 \mathrm{~ms}$ | $\leq 1$ | W |
| $\mathbf{P}_{\text {GAVM }}$ |  |  | 0.5 | W |
| $\begin{aligned} & \overline{\mathbf{T}_{\mathrm{vJ}}} \\ & \mathbf{T}_{\mathrm{vM}} \\ & \mathbf{T}_{\text {sta }} \end{aligned}$ |  |  | -40...+125 | ${ }^{\circ} \mathrm{C}$ |
|  |  |  |  | 125 | ${ }^{\circ} \mathrm{C}$ |
|  |  |  | -40...+125 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{V}_{\text {ISoL }}$ | $\begin{aligned} & 50 / 60 \mathrm{~Hz}, \mathrm{RMS} \\ & \mathrm{I}_{\text {ISol }} \leq 1 \mathrm{~mA} \end{aligned}$ | $\mathrm{t}=1 \mathrm{~min}$ | 3000 | $\mathrm{V} \sim$ |
|  |  | $\mathrm{t}=1 \mathrm{~s}$ | 3600 | V~ |
| $\mathrm{M}_{\mathrm{d}}$ | Mounting torque | (M5) | 2-2.5 | Nm |
|  |  | (10-32 UNF) | 18-22 | $\mathrm{lb} . \mathrm{in}$. |
| Weight |  |  | 50 | g |

## Features

- Package with DCB ceramic base plate
- Isolation voltage 3600 V ~
- Planar passivated chips
- $1 / 4$ " fast-on terminals
- UL registered E 72873


## Applications

- Supply for DC power equipment
- DC motor control


## Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling

Dimensions in mm (1 mm = 0.0394")


Data according to IEC 60747 and refer to a single thyristor/diode unless otherwise stated.
(1) for resistive load

IXYS reserves the right to change limits, test conditions and dimensions.

| Symbol | Test Conditions | Charact | ristic | alues |
| :---: | :---: | :---: | :---: | :---: |
| $I_{R}, I_{\text {d }}$ | $\begin{array}{ll}V_{R}=V_{\text {RRM }} ; \mathrm{V}_{\mathrm{D}}=\mathrm{V}_{\text {DRM }} & \begin{array}{l}\mathrm{T}_{\mathrm{VJ}}=\mathrm{T}_{\mathrm{VJM}} \\ \\ \mathrm{T}_{\mathrm{VJ}}=25{ }^{\circ} \mathrm{C}\end{array}\end{array}$ | $\begin{aligned} & \leq \\ & \leq \end{aligned}$ | 5 0.3 | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{T}}, \mathrm{V}_{\mathrm{F}}$ | $\mathrm{I}_{\mathrm{T}}, \mathrm{I}_{\mathrm{F}}=45 \mathrm{~A} ; \mathrm{T}_{\mathrm{VJ}}=25^{\circ} \mathrm{C}$ | $\leq$ | 1.45 | V |
| $\begin{aligned} & \mathbf{V}_{\mathrm{T} 0} \\ & \mathbf{r}_{\mathrm{T}} \end{aligned}$ | For power-loss calculations only ( $\left.\mathrm{T}_{\mathrm{v},}=125^{\circ} \mathrm{C}\right)$ |  | $\begin{array}{r} 0.85 \\ 13 \end{array}$ | $\begin{gathered} \mathrm{V} \\ \mathrm{~m} \Omega \end{gathered}$ |
| $\mathrm{V}_{\text {GT }}$ | $\begin{array}{ll}\mathrm{V}_{\mathrm{D}}=6 \mathrm{~V} ; & \mathrm{T}_{\mathrm{vJ}}=25^{\circ} \mathrm{C} \\ & \mathrm{T}_{\mathrm{VdJ}}=-40^{\circ} \mathrm{C}\end{array}$ | $\leq$ | 1.0 | V |
| $\mathrm{I}_{\mathrm{GT}}$ | $\begin{array}{ll}\mathrm{V}_{\mathrm{D}}=6 \mathrm{~V} ; & \mathrm{T}_{\mathrm{vJ}}=25^{\circ} \mathrm{C} \\ & \mathrm{T}_{\mathrm{vJ}}=-40^{\circ} \mathrm{C} \\ & \mathrm{T}_{\mathrm{vJ}}=125^{\circ} \mathrm{C}\end{array}$ | $\leq$ $\leq$ $\leq$ | 65 80 50 | mA mA mA |
| $\begin{aligned} & \overline{\mathbf{V}_{\mathrm{GD}}} \\ & \mathbf{I}_{\mathrm{GD}} \end{aligned}$ | $\begin{array}{ll} \mathrm{T}_{\mathrm{VJ}}=\mathrm{T}_{\mathrm{VJM}} ; & \mathrm{V}_{\mathrm{D}}=2 / 3 \mathrm{~V}_{\text {DRM }} \\ \mathrm{T}_{\mathrm{VJ}}=\mathrm{T}_{\mathrm{VJM}} ; & \mathrm{V}_{\mathrm{D}}=2 / 3 \mathrm{~V}_{\mathrm{DRM}} \end{array}$ | $\begin{aligned} & \leq \\ & \leq \end{aligned}$ | 0.2 5 | V mA |
| $\mathrm{I}_{\mathrm{L}}$ | $\begin{aligned} & \mathrm{I}_{\mathrm{G}}=0.3 \mathrm{~A} ; \mathrm{t}_{\mathrm{G}}=30 \mu \mathrm{~s} ; \\ & \mathrm{di}_{\mathrm{G}} / \mathrm{dt}=0.3 \mathrm{~A} / \mu \mathrm{s} ; \end{aligned}$ | $\leq$ $\leq$ $\leq$ | $\begin{aligned} & 150 \\ & 200 \\ & 100 \end{aligned}$ | mA <br> mA <br> mA |
| $\mathrm{I}_{\mathrm{H}}$ | $\mathrm{T}_{\mathrm{VJ}}=25^{\circ} \mathrm{C} ; \mathrm{V}_{\mathrm{D}}=6 \mathrm{~V} ; \mathrm{R}_{\mathrm{GK}}=\infty$ | $\leq$ | 100 | mA |
| $\mathrm{t}_{\mathrm{gd}}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{VJ}}=25^{\circ} \mathrm{C} ; \mathrm{V}_{\mathrm{D}}=1 / 2 \mathrm{~V}_{\text {DRM }} \\ & \mathrm{I}_{\mathrm{G}}=0.3 \mathrm{~A} ; \mathrm{di}_{\mathrm{G}} / \mathrm{dt}=0.3 \mathrm{~A} / \mu \mathrm{s} \end{aligned}$ | $\leq$ | 2 | $\mu \mathrm{s}$ |
| $\mathbf{t}_{\mathrm{q}} \mathbf{Q}_{\mathrm{r}}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{VJ}}=125^{\circ} \mathrm{C}, \mathrm{I}_{\mathrm{T}}=15 \mathrm{~A}, \mathrm{t}_{\mathrm{P}}=300 \mu \mathrm{~s}, \mathrm{~V}_{\mathrm{R}}=100 \mathrm{~V} \\ & \mathrm{di} / \mathrm{dt}=-10 \mathrm{~A} / \mu \mathrm{s}, \mathrm{dv} / \mathrm{dt}=20 \mathrm{~V} / \mu \mathrm{s}, \mathrm{~V}_{\mathrm{D}}=2 / 3 \mathrm{~V}_{\mathrm{DRM}} \end{aligned}$ | typ. | $\begin{array}{r} 150 \\ 75 \end{array}$ | $\begin{aligned} & \mu \mathrm{S} \\ & \mu \mathrm{C} \end{aligned}$ |
| $\mathrm{R}_{\text {thJc }}$ | per thyristor (diode); DC current |  | 1.15 | K/W |
|  |  |  | 0.29 | K/W |
| $\mathbf{R}_{\text {thJk }}$ | per thyristor (diode); DC current |  | 1.55 0.39 | K/W K/W |
| $\mathrm{d}_{\text {s }}$ | Creeping distance on surface |  | 12.6 | mm |
| $\mathrm{d}_{\text {A }}$ | Creepage distance in air |  | 6.3 | mm |
| a | Max. allowable acceleration |  | 50 | $\mathrm{m} / \mathrm{s}^{2}$ |



Fig. 1 Gate trigger range


Fig. 2 Gate controlled delay time $\mathrm{t}_{\mathrm{gd}}$


Fig. 3 Forward current versus voltage drop per diode


Fig. 6 Power dissipation versus direct output current and ambient temperature



Fig. 4 Surge overload current


Fig. $5 I^{2} t$ versus time per diode


Fig. 7 Max. forward current versus heatsink temperature

Constants for $\mathrm{Z}_{\mathrm{t} \mathrm{t}, \mathrm{H}}$ calculation:

| i | $\mathrm{R}_{\mathrm{thi}}(\mathrm{K} / \mathrm{W})$ | $\mathrm{t}_{\mathrm{i}}(\mathrm{s})$ |
| :---: | :--- | :--- |
| 1 | 0.005 | 0.008 |
| 2 | 0.2 | 0.05 |
| 3 | 0.875 | 0.06 |
| 4 | 0.47 | 0.25 |

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